

DZ2636000L

Zener Diode DZ2636000L

Unit : mm

### Silicon epitaxial planar type For constant voltage / For surge absorption circuit DZ27360 in ML2 type package

#### Features

- · Excellent rising characteristics of zener current IZ
- Low zener operating resistance RZ
- Halogen-free / RoHS compliant
- (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol : JG
- Packaging

Embossed type (Thermo-compression sealing) : 10 000 pcs / reel (standard)

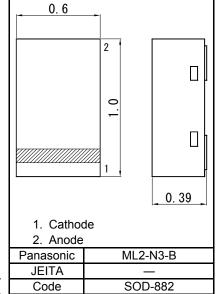
#### ■ Absolute Maximum Ratings Ta = 25 °C

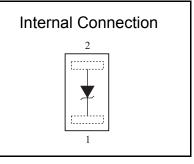
Parameter	Symbol	Rating	Unit
Repetitive peak forward current	IFRM	200	mA
Total power dissipation *1	PT	100	mW
Electrostatic discharge *2	ESD	±8	kV
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note) \*1 PT = 100 mW achieved with a printed circuit board.

\*2 Test method:IEC61000\_4\_2

( C = 150 pF , R = 330  $\Omega$  , Contact discharge : 10 times )





#### Electrical Characteristics Ta = $25 \circ C \pm 3 \circ C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 2 mA	34.20		37.80	V
Zener operating resistance	RZ	IZ = 2 mA			250	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			250	Ω
Reverse current	IR	VR = 27 V			0.05	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 2 mA		35.4		mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. Absolute frequency of input and output is 5 MHz.

3. \*1 The temperature must be controlled 25  $^\circ\text{C}$  for VZ mesurement.

VZ value measured at other temperature must be adjusted to VZ ( 25  $^\circ$ C )

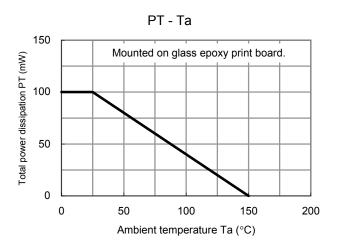
\*2 VZ guaranteed 20 ms after current flow.

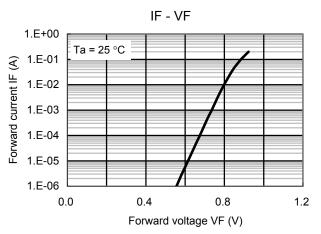
\*3 Tj = 25 °C to 150 °C

**Panasonic** 

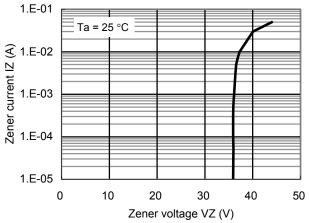
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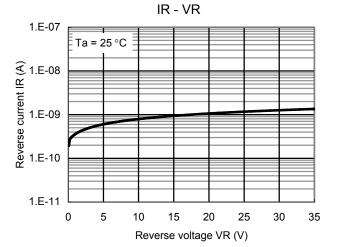
## Technical Data (reference)

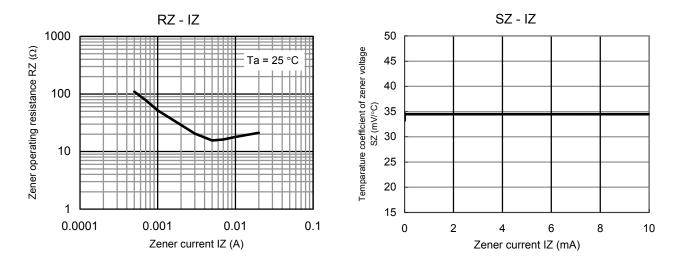












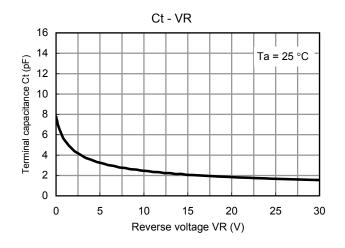
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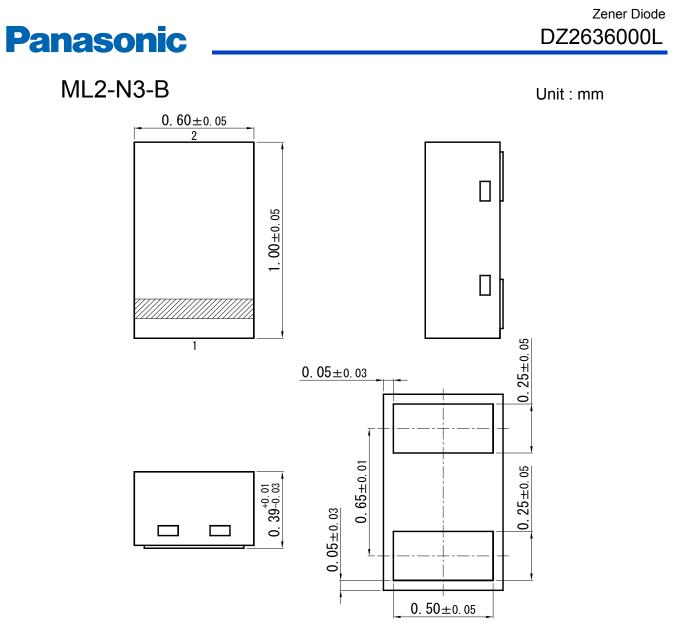
Established : 2013-04-20 Revised : ###-##-## Doc No. TT4-EA-14646 Revision. 1



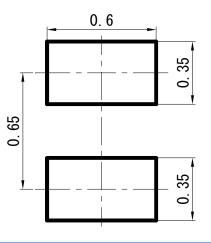
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## Technical Data (reference)





■ Land Pattern (Reference) (Unit : mm)



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